

# SELECTED ITEM DRAWING

					
Unless otherwise specified <b>DIMENSIONS ARE IN INCHES (MM)</b>	<b>TOLERANCES:</b> .XX +/- 0.010 .XXX +/- 0.005 .XXXX +/- 0.002 ANGLES +/- .5 DEG	Drawing practices per <b>ASME Y14.100</b>	<b>5 GHz to 18 GHz, Voltage Variable Attenuator</b>		
			<table border="1" style="width: 100%; border-collapse: collapse;"> <tr> <td style="width: 20%; text-align: center;">                     SIZE <b>A</b> </td> <td style="text-align: center;">                     DRAWING NUMBER <b>SID000074</b> </td> </tr> </table>	SIZE <b>A</b>	DRAWING NUMBER <b>SID000074</b>
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**SID000074** **Rev. A**  
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## 1. SCOPE

### 1.1. Scope

This drawing establishes the requirements for the 5 GHz to 18 GHz, GaAs, MMIC, Voltage Variable Attenuator, assembled hermetically in the LH250 package, to be screened in accordance with MIL-PRF-38535, Class Level S, to the requirements specified in 4.1, 4.2, and 4.3 herein.

### 1.2. Analog Devices Part Number

<u>Generic Part Number</u>	<u>Screened Part Number</u>
ADH812S	HMC8631LH250

## 2. APPLICABLE DOCUMENTS

### 2.1. Government Documents

Unless otherwise specified, the following drawings and standards, of the issue in effect on the date of the accepted purchase order, in the Department of Defense Index of Specifications and Standards (DODISS) and supplement thereto, shall form a part of this drawing to the extent specified herein.

#### **DEPARTMENT OF DEFENSE TEST METHOD STANDARD**

MIL-STD-883            Microcircuits

#### **DEPARTMENT OF DEFENSE PERFORMANCE SPECIFICATIONS**

MIL-PRF-38535            Integrated Circuits (Microcircuits) Manufacturing, General Specification For

### 2.2. Non-Government Documents

The following documents, of the issue in effect on the date of the purchase order, form a part of this drawing to the extent specified herein:

#### **Analog Devices Inc.**

[ADI Standard Space Products Program](#) – *ASD-Lite*.

HMC812LC4            Data Sheet    Commercial Product Datasheet            v03.0614 (Reference Only)

### **3. REQUIREMENTS**

#### **3.1. General Requirements**

The devices delivered shall comply to this specification.

#### **3.2. Design Construction and Physical Dimensions**

The design construction and physical dimensions shall be as defined in Figure 1 herein.

#### **3.3. Traceability**

Each delivered device shall be traceable to the wafer lot and wafer number. Inspection lot records shall be maintained to provide traceability to the specific wafer and wafer lot from which the chips originated as well as traceability to package and materials.

#### **3.4. Burn-In and Life Test Circuit**

The burn-in and life test circuit and conditions shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test methods 1005 and 1015 per MIL-STD-883.

### **4. QUALITY ASSURANCE PROVISIONS**

#### **4.1. Wafer Lot Acceptance Testing**

The wafer lot acceptance testing shall consist of Class Level S inspections per MIL-STD-883 TM 5007.

#### **4.2. Flight Screening Requirements**

Flight screening requirements shall be per MIL-STD-883 TM 5004 for Class level S microcircuits.

##### **4.2.1. Electrical Test Requirements**

Electrical test requirements are defined in Table I herein.

##### **4.2.2. Electrical Performance Characteristics**

Electrical performance characteristics are specified on Table II herein.

##### **4.2.3. Burn-In Delta Requirements**

Pre and Post Burn-In Electrical test and delta parameters shall consist of the tests specified in Table III herein.

#### **4.3. Quality Conformance Inspection (QCI)**

Group B and Group D tests shall be performed per MIL-STD-883 TM 5005 for Class level S microcircuits.

##### **4.3.1. Post Steady State Life Electrical Test**

Post steady state life electrical tests shall consist of the tests specified per Table II tested at room temperature only.

Devices must meet delta parameter requirements in accordance with Table III herein.

## 5. MIL-PRF-38535 ASD-LITE EXCEPTIONS

The manufacturing flow described in the ADI STANDARD SPACE PRODUCTS PROGRAM is to be considered a part of this specification.

### 5.1. Wafer Fabrication

Foundry information is available upon request.

### 5.2. Flight Screening Flow

Non-Destruct Bond Pull: Not performed.

Reverse Bias Burn-In: Not applicable.

### 5.3. Group B

Subgroup 2: Resistance to solvents is not applicable.

### 5.4. Group D

Subgroup 5: Not applicable.

Subgroup 7: Not applicable.

Subgroup 8: Not applicable.

Subgroup 9: Not applicable.

## 6. PREPARATION FOR DELIVERY

The preparation for delivery, packaging, preservation, ESD protection and handling shall be in accordance with MIL-PRF-38535.

### 6.1. Part Marking

Devices shall be marked as specified on Figure 1 herein.

### 6.2. Inspection Data Requirements

The following data shall accompany each shipment.

- a. A Certificate of Conformance (C of C) certifies that the lot(s) meets all requirements of this specification.
- b. Wafer Lot Acceptance data including photos from SEM Inspection defined in 4.1 herein.
- c. Summary of electrical test requirements defined in 4.2 herein.
- d. Summary of QCI results defined in 4.3 herein.
- e. Failure Analysis with photos (If applicable)
- f. A cover sheet indicating the following purchasing information:
  1. Customer purchase order number.
  2. Analog Devices part number.
  3. Part lot identification codes.
  4. Date & quantity shipped.

**TABLE I: ELECTRICAL TEST REQUIREMENTS**

Test Requirement	Subgroups (in accordance with MIL-PRF-38535, Table III)
Interim Electrical Parameters	1, 4
Final Electrical Parameters	1, 4 <u>1/2/</u>
Group A Electrical Parameters	1, 2, 3, 4, 5, 6
Group B End-Point Electrical Parameters	1, 4 <u>2/</u>
Group D End-Point Electrical Parameters	1, 4

TABLE I Notes:

1/ PDA applies to Table I subgroup 1 and Table III delta parameters.

2/ See Table III for delta parameters

**TABLE II: ELECTRICAL PERFORMANCE CHARACTERISTICS (-40 °C, +25 °C AND +85 °C)**

Parameter	Test Conditions <u>1/2/</u> Unless otherwise specified	Group A Subgroups	Limits		Units
			Min	Max	
Insertion Loss	RFIN = 7 GHz and 10 GHz V1 = V2 = -3 V P <sub>IN</sub> = 0 dBm	4, 5, 6		2.5	dB
	RFIN = 13 GHz V1 = V2 = -3 V P <sub>IN</sub> = 0 dBm	4, 5, 6		3.5	dB
Maximum Attenuation Range	RFIN = 7 GHz and 10 GHz V1 = V2 = 0 V P <sub>IN</sub> = 0 dBm	4, 5, 6	25	35	dB
	RFIN = 13 GHz V1 = V2 = 0 V P <sub>IN</sub> = 0 dBm	4, 5, 6	27	35	dB
Attenuation Control	RFIN = 7 GHz, 10 GHz, and 13 GHz V1 = 0 V, V2 = -3 V P <sub>IN</sub> = 0 dBm	4, 5, 6		16	dB
Insertion Loss Flatness <u>3/</u>	RFIN = 7 GHz and 10 GHz V1 = V2 = -3 V P <sub>IN</sub> = 0 dBm	4, 5, 6		0.75	dB
	RFIN = 13 GHz V1 = V2 = -3 V P <sub>IN</sub> = 0 dBm	4, 5, 6		1.5	dB
Control Current	V1 = V2 = -3/0 V	1, 2, 3		10	μA

TABLE II Notes:

1/ Test limits apply between at -40 °C and +85 °C

2/ Measurements made at RFIN = 7 GHz, 10 GHz and 13 GHz unless otherwise noted.

3/ It shall be measured as the Insertion Loss delta between 7 GHz and 10 GHz and between 10 GHz and 13 GHz.

**TABLE III: BURN-IN/LIFE TEST DELTA LIMITS 1/2/3/**

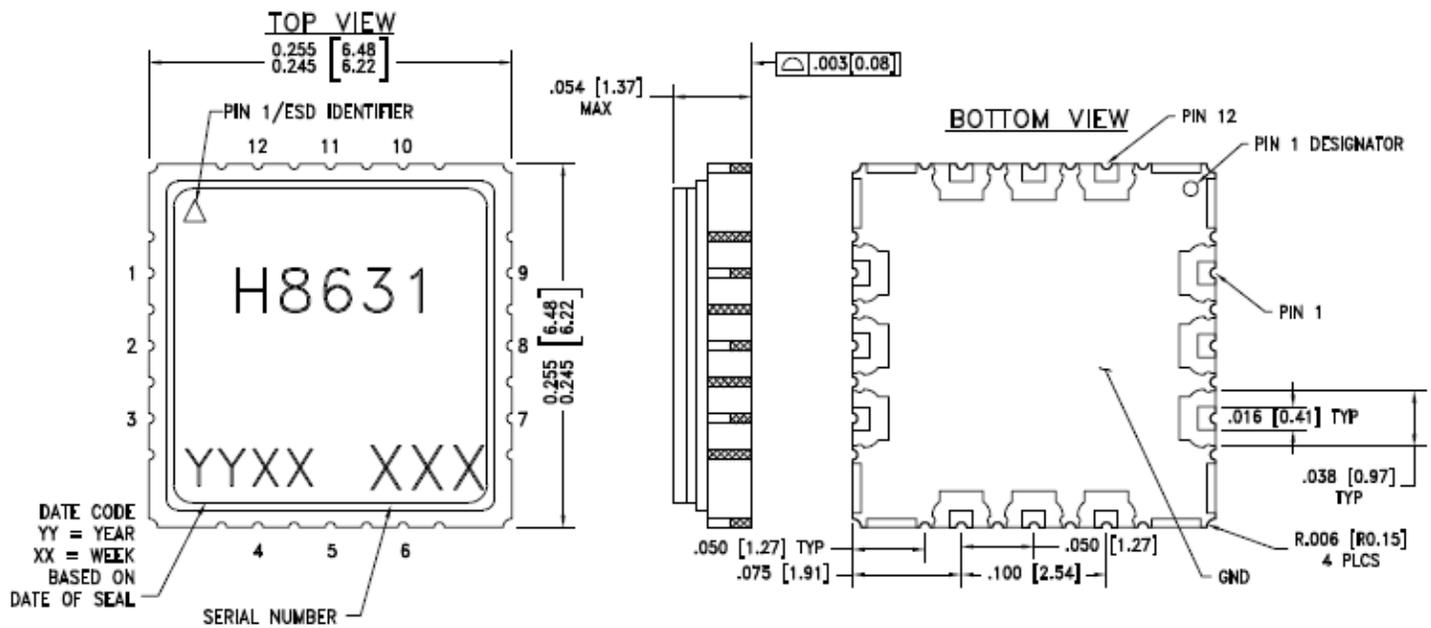
<b>Parameter</b>	<b>Test Conditions</b>	<b>Delta Limits</b>	<b>Units</b>
Insertion Loss	Per Table II	$\pm 1$	dB

TABLE III Notes:

1/ Delta test is performed at  $T_A = +25$  °C only.

2/ Table II limits will not be exceeded.

3/ Deltas calculated at pre/post 240 hours and post 240 hour / post1000 hours.



**NOTES:**

1. PACKAGE BODY MATERIAL: CERAMIC & KOVAR
2. LEAD AND GROUND PADDLE PLATING: GOLD 40-80 MICROINCHES.
3. DIMENSIONS ARE IN INCHES [MILLIMETERS].
4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
5. CHARACTERS TO BE LASER MARKED WITH .018"MIN to .030"MAX HEIGHT REQUIREMENTS. UTILIZE MAXIMUM CHARACTER HEIGHT BASED ON LID DIMENSIONS AND BEST FIT. LOCATE APPROX. AS SHOWN.
6. PAD BURR LENGTH 0.15mm MAX. PAD BURR HEIGHT 0.25mm MAX.
7. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
8. THE SOLDER FILLET BETWEEN PACKAGE AND COVER IS PART OF THE DESIGN SEAL AREA.

Pin #	Function						
1	GND	4	GND	7	GND	10	GND
2	RFIN	5	V1	8	RFOUT	11	GND
3	GND	6	V2	9	GND	12	GND

Figure 1 – Device Outline for the HMC8631LH250

## ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
HMC8631LH250	-40 °C to +85 °C	12-Lead Ceramic Hermetic Leadless Chip Carrier	LH250 (E-12-6)

## Revision History

Revision History		
Rev	Description of Change	Date
A	Initial release.	01/28/2025